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جامعة بوليتكنك فلسطين كلية الهندسة و التكنولوجيا دائرة الهندسة الكهربائية الخليل –فلسطين

اسم المشروع:

Design and Analyze of Microstrip Antenna

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بناء على نظام كلية الهندسة و التكنولوجيا و إشراف و متابعة المشرف المباشر على المشروع و موافقة أعضاء اللجنة الممتحنة, تم تقديم هذا المشروع إلى دائرة الهندسة الكهربائية و ذلك استكمالا لمتطلبات درجة البكالوريوس في تخصص هندسة الاتصالات و الإلكترونيات.

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Graduation Project

Design and Analysis of Microstrip Antenna

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December 2012

DEDICATION

To Our Families and Friends

and for engineer Ala' Alsaheb for helping us in completing this thesis

ACKNOWLEDMENT

We feel grateful to our supervisor

Dr. Osama Ata for his great help and supports

Thanks to our teachers

Our thanks to Palestine Polytechnic University

College of Engineering & Technology

Our thanks to Electrical Engineering Department

Our parents and families

ABSTRACT

The performance and advantages of microstrip patch antennas such as low weight, low profile, and low cost made them the perfect choice for communication systems engineers. They have the capability to integrate with microwave circuits and therefore they are very well suited for applications such as cell devices, WLAN applications, navigation systems and many others.

In this project; a compact rectangular microstrip antenna performance with different types of feeding techniques are designed, for inset and edge feed at 2.4GHz compare the result that get from insert feed with edge feed design and analysis, and decide which design technique is the best, which obtain good bandwidth and return loss.

Coaxial feed is designed to operate from 2 GHz to 12 GHz, and finally a proximity coupled microstrip antenna is designed to operate at 13GHz, and controlling the position of the feed line between the two substrates to optimize the return loss.

CONTENTS

Dedication	Page 1 of 16
Acknowledgement	Page 2 of 16
Abstract	Page 3 of 16
List of contents	Page 4 of 16
List of figures	Page 8 of 16
List of equations	Page 12 of 16
Abbreviations	Page 13 of 16
Preface	Page 16 of 16

1. Chapter 1: Introduction	1
1.1. An Overview	2
1.2. Project description	3
1.3. Project objectives	5
1.4. Technologies	6
1.5. Timing table	7
1.6. Previous studies	11

Chapter 2: Theoretical Background	13
2.1 Microstrip antenna	14
2.2 Waves of microstrip antenna	15
2.3 Surface Waves	16
2.4 Leaky Waves	17
2.5 Advantages and disadvantages of microstrip antenna	17

2.6 Width and length of the patch	18

2.7 Applications	19
2.8 Rectangular microstrip antenna	20
2.9 Feeding Methods	21
2.9.1 Microstrip Line Feeding	22
Quarter-wave Match Feed	23
Inset feed	24
2.9.2 Coaxial Feeding	24
2.9.3 Aperture Coupling	25
2.9.4 Proximity Coupling 2	26
2.10 Methods of Analysis	27
2.10.1 Cavity Model	27
2.10.2 Transmission line Mode	28
The patch	29
Ground planes	31
Edge feed rectangular microstrip patch antenna	32
Inset feed rectangular microstrip patch antenna	35
• The resonance input resistance in R in calculation	

Chapter 3: Software Design	39
3.1 Ansoft Designer software	40
3.2 Designing microstrip transmission line	41
3.2.1Planar EM Design Setup in Designer	42

3.2.2 Model Setup	43
3.2.3 Excitation Setup	45
3.2.4 Analysis Setup	47
3.2.5 Plotting Results	49
3.3 Designing printed dipole antenna	51
3.3.1 layers setup	52
3.3.2Model setup	54
3.3.3 Excitation setup	56
3.3.4 Analysis Setup	57
3.3.5 Plotting Results	59
3.4 Designing rectangular patch with feed line	60
3.3.1 layers setup	61
3.3.2Model setup	62
3.3.3 Excitation setup	68
3.3.4 Analysis Setup	69
3.3.5 Plotting Results	71
3.4 Project's Flow Chart	74
Chapter 4: Microstrip antenna performance with different types of feeding techniques	75
4.1 Introduction	76
4.2 Design Procedure	78
4.2.1 Calculations of inset fed patch antenna	78
4.2.2 Calculation Fed with a Quarter-Wavelength Transmission Line (Edge Fed)	79
4.2.3 Design Of Rectangular Microstrip Inset Feed line	81
4.2.4 Design of rectangular microstrip quarter length (edge feed) line	82
4.2.5 Design of Coaxial cable feed of Patch Antenna	84
4.2.6 Design of Proximity-Coupled Microstrip Antenna	85
4.3 Results and discussion	86

4.3.1 Return loss	92
4.3.2 Radiation Pattern of Rectangular Microstrip Inset Feed line and proximity coupled feed.	102

Chapter 4:Result and Conclusion	105
5.1 An overview	106
5.2 Conclusions	106

References 1	107
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LIST OF FIGURES

Figure 1.1. Edge feed rectangular microstrip patch antenna	3
Figure 1.2. Inset feed rectangular microstrip patch antenna	4
Figure 1.3. Proximity-coupled Feed	4
Figure 2.1. Simple microstripantenna	14
Figure 2.2. The shapes of patch conductors	15
Figure 2.3. Hertz dipole on microstrip substrate	16
Figure 2.4. Surface waves	16
Figure 2.5. Leaky waves	17
Figure 2.6. A physical and effective length of a microstrip patch	19
Figure2.7. Field lines	21
Figure 2.8. Microstrip Line Feed	22
Figure 2.9. Microstrip Line Feed	23
Figure 2.10. Probe fed Rectangular Microstrip Patch Antenna	24
Figure 2.11. Aperture-coupled feed	25
Figure2.12. Proximity-coupled Feed	26
Figure 2.13. Charge distribution and current density creation on the patch	28
Figure 2.14.a Top View of Antenna	29
Figure 2.14.b Side View of Antenna	29
Figure 2.15. Electric field lines in a transmission line	30
Figure 2.16. Patch antenna with a quarter-wavelength	32
Figure 2.17. Rectangular microstrip patch antenna	33

Figure 3.2.1. Model of microstrip line showing cross-section (transverse to propagation).	41
Figure3.2.2. Choose layout technology window	42
Figure 3.2.3. Layers dialog box	43
Figure3.2.4. microstrip line calculator	44
Figure 3.2.5. Rectangle dialog box	45
Figure 3.2.6.Completed microstrip transmission line drawn in Ansoft Designer	46
Figure.3.2.7. 3-D view of completed microstrip transmission line drawn in Ansoft Designer.	. 46
Figure 3.2.8. Fixed mesh with a frequency of 10.0 GHz	47
Figure 3.2.9. Frequency sweep window	48
Figure 3.2.10. Matrix data dialog box	49
Figure 3.2.11. Plotting S11 and S21	50
Figure 3.2.12. Numerical return and insertion loss	51
Figure 3.3.1. Model of printed dipole antenna based on differential feeding	52
Figure 3.3.2. Choose layout technology window	53
Figure 3.3.3 Layers dialog box	53
Figure 3.3.4. A dialog box	55
Fig 3.3.5.Dipole antenna model	55
Figure.3.3.6. Selected edge for port definition	56
Figure 3.3.7. Add port	56
Figure 3.3.8. Differential port setup	57
Figure 3.3.9.Fixed mesh with a frequency of 4.0 GHz	58
Fig 3.3.10. Frequency sweep window	58
Figure 3.3.11. Input impedance of un-optimized printed dipole	59

Figure 3.3.12.Radiation Pattern	59
Figure 3.4.1. Rectangular Microstrip Patch Antenna	60
Figuer 3.4.2 Choose layout technology window	61
Figure 3.4.3. Layers dialog box	62
Figure 3.4.4. Choose layout technology window	63
Figure 3.4.5. Layers dialog box	64
Figure 3.4.6.Substrate definition box	64
Figure 3.4.7. Microstrip Line Calculator	65
Figure 3.4.8. Rectangle dialog box for the patch	66
Figure 3.4.9.Rrectangle dialog box for the feed line	67
Figure 3.4.10. The patch antenna with feed line	67
Figure 3.4.11. The edge port at the end of feed line	68
Figure 3.4.12. The load impedance on the port	69
Figure 3.4.13. Fixed mesh with a frequency of 2GHz	70
Figure 3.4.14. Frequency sweep window	71
Figure 3.4.15. Numerical return and insertion loss	72
Figure 3.4.16. Single value at 2.4 GHz in frequency sweep window	73
Figure 3.4.17. Far-field pattern at 2.4 GHz	73
Figure 4.1. The inset fed patch geometry	77
Figure 4.2.Quarter wavelength fed patch antenna	80
Figure 4.3. Design of inset fed patch microstrip antenna	82
Figure 4.4. The design of the edge feed patch microstrip antenna	83
Figure 4.5 Coaxial cable feed of Patch Antenna	84
Figure 4.6.Proximity-Coupled Microstrip Antenna	85
Figure 4.7. The relationship between the Bandwidth and the inset gap 'g'	84
Figure 4.8. The relationship between resonant frequency and notch width "g"	88

Figure 4.9. The relationship between bandwidth and inset distance "d" for g=Wf/40	89
Figure 4.10. The relationship between bandwidth and inset distance "d" for g=Wf/5	90
Figure 4.11.The return loss of the edge feed patch microstrip antenna	92
Figure 4.12. Return loss when L=2 W_f and g = $W_f/10$	93
Figure 4.13. Return loss when L=4 W_f and g = $W_f/5$	94
Figure 4.14. Return loss when L=4 W_f and g = $W_f/10$	95
Figure 4.15. Return loss when L=4 W_f and g = $W_f/20$	96
Figure 4.16 Return loss when L=4 W_f and g = $W_f/30$	97
Figure 4.17. Return loss when L=4 W_f and g = $W_f/40$	98
Figure 4.18 S-parameter (dB) versus Frequency (1-4 GHz)	99
Figure 4.19 S-parameter (dB) versus Frequency (GHz)	100
Figure 4.20. Return loss at the resonant frequency	101
Figure.4.21 Radiation pattern phi 0 and 90 E-plane for d= Wf and g= W / 40	102
Figure.4.22 Radiation pattern phi 0 and 90 E-plane for d=Wf and g = W_f/5	103
Figure.4.23 Radiation pattern phi 0 and 90 E-plane for d=Wf and g = W_f/30	103
Figure.4.24 Radiation pattern phi 0 and 90 E-plane for d=4Wf and g = W_f/40	104
Figure.4.25 Radiation pattern phi 0 and 90 E-plane for the of Proximity-Coupled Microstrip Antenna	104

LIST OF EQUATIONS

Eq. (2.1)	18
Eq. (2.2)	18
Eq. (2.3)	18
Eq. (2.4)	18
Eq. (2.5)	30
Eq. (2.6)	31
Eq. (2.7)	31
Eq. (2.8)	31
Eq. (2.9)	31
Eq. (2.10)	32
Eq. (2.11)	33
Eq. (2.12)	34
Eq. (2.13)	34
Eq. (2.14)	34
Eq. (2.15)	35
Eq. (2.16)	35
Eq. (2.17)	35
Eq. (2.18)	36
Eq. (2.19)	36
Eq. (2.20)	36
Eq. (2.21)	37
Eq. (2.22)	37
Eq. (2.23)	37

Eq. (2.24)	38
Eq. (2.25)	38
Eq. (2.26)	38
Eq. (2.27)	38
Eq. (4.1)	78
Eq. (4.2)	78
Eq. (4.3)	78
Eq. (4.4)	79
Eq. (4.5)	79
Eq. (4.6)	79
Eq. (4.7)	80
Eq. (4.8)	81
Eq. (4.9)	81
Eq. (4.10)	81

List of Abbreviations

ACMSA	aperture coupled microstrip antenna.
AR	axial ratio.
BW	bandwidth.
E-	field electrical field.
H-	field magnetic field .
FDTD	finite-difference time-domain.
FEM	finite element method.
MIC	microwave-integrated circuit.
МоМ	method of moments.
MSA	microstrip antenna.
RMSA	rectangular microstrip antenna.
VSWR	voltage standing-wave ratio.
WI-FI	Wireless Fidelity .
WI-MAX	Wireless Fidelity Worldwide Interoperability for Microwave Access.
HFSS	high frequency structural simulator.
PDAs	Personal digital assistance .
DSL	Digital Subscriber Line .
WLAN	wireless local area network.
LOS	line-of-sight.
WMAN	Wireless Metropolitan Area Network.
WAN	Wide Area Network.
IEEE	Institute of Electrical and Electronic Engineering.
LAN	Local Area Network.
IE	Integral Equation.

electromagnetic.

Page **15** of **16**

ΕM

Preface

Chapter one:

Brief introduction to Microstrip antenna, Project objectives, Technologies, time plan and previous studies are introduced in this chapter.

Chapter two:

Microstrip antenna is explained in some details for the case of a rectangular microstrip antenna, Waves of microstrip antenna, Advantages and disadvantages of microstrip antenna, Microstrip antenna applications, Feeding Methods are also introduced. Finally, methods of Analysis, and an explanation for the transmission line Mode are introduced in this chapter.

Chapter three:

Ansoft Designer software is introduced; the way to design microstrip transmission line, printed dipole antenna and rectangular patch with feed line is also explained. In addition, the flow chart of simulation functions is explained.

Chapter four:

It shows and discusses simulation result in order to specify Microstrip antenna performance with different types of feeding techniques.

Chapter five:

Conclusions are introduced in this chapter.

Chapter 1

Introduction

- 1.1. An Overview
- 1.2. Project description
- 1.3. Project objective
- 1.4. Technologies
- 1.5. Timing table
- 1.6. Previous studies

Chapter One

Introduction

1.1 Overview.

The microstrip antenna, is an antenna with a small size, lightweight, low profile, and low manufacturing cost, these characteristics of this antenna are the reason that it is being used widely especially in industrial sectors, such as, mobile satellite communications, direct broadcast satellite services, global positioning system.

A microstrip antenna consists of a radiating metallic patch or an array of patches, the patch acts approximately as a resonant cavity, on one side of a thin nonconducting, supporting substrate panel with a ground plane on the other side of the panel .[1]

The metallic patch is normally made of copper-foil plated with a corrosion material, such as gold, tin, or nickel. Each patch can be made into a variety of shapes with the most popular shapes being rectangular and circular. [2]

The CAD tools can help the designer to complete a micro strip array in couple of weeks, knowing that the designing process used to take months and designers used cut, try method, which was very expensive, and time consuming.

Deschamps first proposed the concept of microstrip antennas in 1953. A patent was issued in France in 1955 in the names of Gutton and Biassinot. Development during the 1970s was accelerated due to good substrate with low loss tangent available. [1]

1.2 Project description.

The aim of this project is optimize and analysis of rectangular patch microstrip antenna, also to improve the bandwidth of the antenna.

At the beginning the dimensions of the patch must be calculated (W, L), to study the effect of these dimensions, the length determines the resonant frequency, the width is critical in terms of power efficiency, antenna impedance and bandwidth.

During the designing process of the Microstrip Antenna, the research team will try to increase the bandwidth of the Antenna as much as possible using mathematical analysis and HFSS Designing Software, and using different design and feeding techniques to enhance the bandwidth of the microstrip antenna such as proximity coupled feed, edge feed microstrip antenna as shown in Fig.1.1, insert feed microstrip antenna as shown in Fig.1.2, then compare the return loss, bandwidth , and the performance for each design.

In inset feed design, we change the notch width and inset distance to make manual optimization of return loss and bandwidth of the antenna. In the proximity-coupled feed two dielectric substrates are used, such that the feed line is between the two substrates and the radiating patch is on top of the upper substrate as shown in figure 1.3. [3]



Figure 1.1 Edge feed rectangular microstrip patch antenna.



Figure 1.2. Inset feed rectangular microstrip patch antenna.



Figure 1.3. Proximity-coupled Feed.

The main advantage of this feed technique is that it eliminates spurious feed radiation and provides very high bandwidth (as high as 13%), due to overall increase in the thickness of the microstrip patch antenna. This scheme also provides choices between two different dielectric media, one for the patch and one for the feed line to optimize the individual performances. On the other hand, this feed scheme is difficult to fabricate because of the two dielectric layers, which need proper alignment. Also, there is an increase in the overall thickness of the antenna. Matching can be achieved by controlling the length of the feed line and the width-to- line ratio of the patch. [4].

1.3 Project objectives.

- 1. Design and analysis of edge feed microstrip antenna.
- Design and analysis of inset feed microstrip antenna, we will change the notch width and insert distance to make manual optimization of return loss and bandwidth of the antenna.
- 3. Compare the result that get from insert feed with edge feed design and analysis, and decide which design technique is the best, which obtain good bandwidth and return loss.
- 4. The project will use the best possible matching techniques in such a way so that there will be a minimum return loss. [5]
- 5. Design proximity coupled feed microstrip antenna, and observing how this design improve the bandwidth.

1.4 Technologies.

Ansoft Designer Software :

Ansoft Designer software is an integrated schematic and design management front-end for ANSYS's best-in-class simulation technologies, ANSYS HFSS, ANSYS Q3D Extractor, and ANSYS SI wave. Ansoft Designer is the foundation for a highly accurate design flow that allows you to precisely model and simulate complex analog, RF and mixed-signal applications as well as perform signal-integrity analysis and system verification of high-performance IC/package/board designs. This flexible, easy-touse tool includes schematic capture and layout editing, net list generation and sophisticated data visualization and analysis tools.

HFSS.13 Designer:

HFSS (High Frequency Structure Simulator) software is the industry-standard simulation tool for 3-D full-wave electromagnetic field simulation and is essential for the design of high frequency and highspeed component design. This software automatically divides the geometric model into a large number of tetrahedron, where a single tetrahedron is a four-sided pyramid. This collection of tetrahedron is referred to as the finite element mesh. Each element can contain a different material. Therefore, the interface between two different materials must coincide with element boundaries. The value of a vector field quantity (such as the H-field or E-field) at points inside each tetrahedron is interpolated from the vertices of the tetrahedron. By representing field quantities in this way, the system can transform Maxwell's equations into matrix equations that are solved using traditional numerical methods. With HFSS, engineers can extract scattering matrix parameters (S, Y, Z parameters); visualize 3-D electromagnetic fields (near- and far-field). Each HFSS solver is based on a powerful, automated solution process where you are only required to specify geometry, material properties and the desired output. From there HFSS will automatically generate an appropriate, efficient and accurate mesh for solving the problem using the selected solution technology.

1.5 Activities Description and Time Table Plane.

In this part, we will state the project activates, the period of each activity, the starting and the ending time for each of them and the activity's dependence.

Task		Time (Weeks)														
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
A1																
A2																
A3																
A4																
A5																
A6																
A7																

Table 1.1	Time plan	(first semester)	
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Table 1.2. Activates description (first semester)

Dates	Activity ID	Activities Description
Months		
	A1	Selecting of the project.
5/2-12/2		
	A2	Collecting surveying information, abstract & project
12/2-26/2		plan.
	A3	Collecting details information with some analyzing.
26/2-17/3		
	A4	Learning and working with new software.
17/3-5/4		
	A5	Designing a microstrip antenna as a block diagram
5/4-18/4		
	A6	Write the remaining documentation, then
18/4-25/4		delivering to the supervisor.
	A7	Delivering to department and prepare our self for final
25/4-4/5		presentation.

Task	Time (Weeks)															
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
A8																
A9																
A10																
A11																
A12																
A13																
A14																

Table 1.3 Time plan (second semester)

Table 1.4. Activates description (second semester)

Dates	Activity ID	Activities Description
Months		
	A8	Learning and working with new software.
2/9-8/9		
	A9	Design of edge feed microstrip antenna.
9/9-22/9		
	A10	Design of inset feed microstrip antenna.
23/9-6/10		
	A11	Write the first part of chapter four
7/10-13/10		
	A12	Design of Proximity-Coupled Microstrip Antenn.
14/10-3/11		
	A13	Design of Coaxial cable feed of Patch Antenna.
4/11-24/11		
25/11-23/12	A14	Write the remaining documentation, then delivering to the supervisor.

Previous studies.

In [6], Inset feed microstrip antenna and insert feed was proposed in this paper, researchers designed Insert feed microstrip rectangular patch antenna work at 5.2 GHZ, with -1 2.02 dB return loss. An edge feed work at 5.2 GHZ and -10.87 dB. As a conclusion at this paper, different feeding techniques are applied to rectangular patch antenna and its performance characteristics are observed at fixed frequency. Radiated power is high for the case of edge feeding compare with insert feed. In our project insert feed and edge feed are designed at the same dimensions and frequency, on FR4 epoxy of $\varepsilon r = 4.4$ and h = 1.5 at 2.4 GHz, patch antenna has length (L) of 3.8 cm and its width(W) of 2.95cm and its resonant frequency of 2.4GHz and we will compare return loss and bandwidth of their two techniques.

In [7], Researchers at this paper designed a square patch multilayer proximity coupled microstrip antenna operating at 7GHz. Having a length and width of the patch is L=W=13mm. they have used feed substrate with dielectric medium of 3.2 and dielectric medium for antenna substrate is 2.33 and have an air gap of height 2.2mm with dielectric medium 1.10.With thickness of feed substrate=0.55mm, and thickness of antenna substrate=0.35mm. With comparing to our project, we design rectangular not square patch antenna, and we use dielectric constant of 2.2 for both layers of substrate.

In [8], this paper presented design of two edge-fed patch and compared their return loss and performance .The microstrip patch element dimensions were 20.3, 20.3 mm, the microstrip feed line had a width of 9.4 mm, and was inset into the patch element a distance of 7.1 mm. The ground plane and substrate measured approximately 100 mm, but they have different dielectric substrate constant, the first one with thin (1.575 mm) and the second thick (3.125 mm) Rogers RT/Duroid 5880 substrates. Their results confirm that the use of a thick substrate can increase the impedance bandwidth to 3.4% (defined as being 10 dB return loss) from approximately 2% when using the thin substrate. In our project we design inset feed rectangular microstrip patch has been designed on FR4 epoxy of $\varepsilon r = 4.4$ and h = 1.5 mm. It decides to design the rectangular patch for 2.4 GHz. Then we compare their performance with single patch microstrip antenna.

In [9], In this paper inset feed rectangular patch antenna was designed with a Rogers RT/duroid 5870(tm) dielectric material (ϵ r =2.2), with dielectric loss tangent of 0.001 is selected as the substrate with 62 mil height ,and antenna operates at the specified operating frequency f0 =2.4835 GHz can be designed by the , with Inset distance 1.22 cm, Inset gap 0.243 cm, feed Length 3.68 cm feed width 0.486 cm. In this work it is found that the insertions of inspired material structure at ground plane on rectangular microstrip patch antenna ultimately enhances bandwidth significantly. This had also been proven that the focusing effect of metamaterial really reduces return Loss as well as improve Gain and Directivity of such types of antenna.

Chapter 2

Theoretical Background

- 2.1 Microstrip antenna
- 2.2 Waves of microstrip antenna
- 2.3 Surface Waves
- 2.4 Leaky Waves
- 2.5 Advantages and disadvantages of microstrip antenna
- 2.6 Width and length of the patch
- 2.7 Applications
- 2.8 Rectangular microstrip antenna
- 2.9 Feeding Methods.
- 2.10 Methods of Analysis.

Chapter tow

Theoretical Background

2.1 Microstrip antenna.

Deschamps first proposed the concept of microstrip antennas in 1953. A patent was issued in france in 1955 in the names of Gutton and Biassinot. Development during the 1970s was accelerated due to good substrated with low loss tangent available. The first practical antennas were developed by Howell and Munson. Development of microstrip antennas, aimed at exploiting their advantages such as light weight, low volume, low cost [10].

As shown in Figure 2.1, a microstrip antenna in its simplest configuration consists of a radiating patch on one side of a dielectric substrate, which has a ground plane on the other side. The patch conductors, normally of copper or gold, can assume regular shapes such as circular and rectangular and triangular as shown in figure 2.2 are generally used to simplify analysis and performance prediction. Microstrip patch antennas radiate primarily because of the fringing fields between the patch edge and the ground plane [11].



Figure 2.1. Simple microstrip antenna.



Figure 2.2. The shapes of patch conductors.

The dielectric constant of the substrate should be low (ε_r <2.5) to enhance the fringe fields, various types of substrates having a large range of dielectric constant and loss tangent values have been developed. A thick dielectric Substrate having a low dielectric constant and this provides better efficiency, larger bandwidth and better radiation [12].

During the last decade, the cost to develop the microstrip antenna has dropped, because of the advancement of the microstrip antenna technology and the reduction in cost of the Substrate material and manufacturing process, and the simplified design process using the newly developed computer-aided design (CAD) tools [13].

2.2 Waves of microstrip antenna

The mechanisms of transmission and radiation in a microstrip can be understood by Considering a point current source (Hertz dipole) located on top of the grounded dielectric Substrate as shown in Figure 2.3, this source radiates electromagnetic waves [14].



Figure 2.3. Hertz dipole on microstrip substrate.

2.3 Surface Waves:

The waves transmitted slightly downward, having elevation angles θ between(π /2and π), meet the ground plane, which reflects them, and then meet the dielectric-to-air boundary The fields remain mostly trapped within the dielectric, as shown in Figure 2.4 , The vector α , pointing upward, indicates the direction of largest attenuation. The wave propagates horizontally along β , with little absorption in good quality dielectric [3].



Figure 2.4. Surface waves.

2.4 Leaky Waves:

Waves directed more sharply downward, with θ angles between π - and $\pi/2$, are also reflected by the ground plane but only partially by the dielectric-to-air boundary. The leaky waves leak from the substrate into the air (Fig 2.5), they contribute to radiation. The leaky waves are also non uniform plane waves for which the attenuation direction α points downward as shown in figure 2.5 [15].



Figure 2.5. Leaky waves.

2.5 Advantages and disadvantages of microstrip antenna

The performance and advantages of microstrip patch antennas made them the perfect choice for communication systems engineers. They have the capability to integrate with microwave circuits and they are very well suited for applications such as cell devices, WLAN applications, navigation systems and many others [16]. The advantages are:

- Light weight and low volume
- Low fabrication cost.

- Linear and circular polarizations are possible with simple feed.
- Dual polarization antennas can be easily made.

However, microstrip antennas also have some limitations compared to conventional microwave antennas:

- Narrow bandwidth that can be improved by increasing the substrate thickness feed radiation and the substrate thickness.
- Somewhat lower gain.
- Lowe power handling capability.

2.6 Width and length of the patch

Patch width has a minor effect on resonant frequency and radiation pattern of the antenna. A larger patch width increases the power radiated and decreased resonant resistance, increased bandwidth, decreased Gain and increased radiation efficiency [15].

The patch length determines the resonant frequency, a larger patch length decreases the resonant frequency, the patch length is

$$L = \frac{C}{2f_r \sqrt{\epsilon}_{re}}$$
(2.1)

The fields are not confined to the patch. A fraction of the fields lie outside the physical diminsions L × W (fringing fields). The effect of the fringing field can be included by effective dielectric constant ε_{re} . The effective patch length (L_e) also including the effect of fringing field, it becomes L + 2 Δ I. Then,

$$l_{eff} = \frac{C}{2f_r \sqrt{E_{re}}} - 2\Delta L$$

$$(2.2)$$

$$f_r = \frac{C}{2(L+2\Delta L)\sqrt{E_{re}}}$$

$$(2.3)$$


Figure 2.6 shows the width, length and effective length of the patch antenna.



Figure 2.6. A physical and effective length of a microstrip patch.

2.7 Applications

for many applications, the advantages of microstrip antennas far outweigh their limitations. Initially, microstrip antennas found widespread applications in military systems such as missiles, rockets, aircraft, and satellites. These antennas are being increasingly used in the

commercial sector due to the reduced cost of substrate material and advanced fabrication technology [16].

Some system applications for which microstrip antennas have been developed include:

- Satellite communication, direct broadcast services (DBS)
- Doppler and other radars.
- Radio altimeters.
- Command and control systems.
- Missiles and telemetry.
- Remote sening and environmental instrumentation.
- Mobile radio (pagers, telephones).

2.8 Rectangular microstrip antenna.

the simplest microstrip patch configuration shown in Fig 2.6 is the rectangular patch microstrip antenna. The basic antenna elemnt is a strip conductor of dimensions $L \times W$ on a dielectric substrate of dielectric constant C_r and thickness h backed by a ground plane. When the patch is excited by a feed, a charge distribution is established on the underside of the patch and the ground plane [15]. The underside of the patch is positively charged and the ground plane is negatively charged. The attractive forces between these sets of charges holds a large percentage of the charge between the two surfaces. Still, the repulsive force between positive charges on the patch pushes some of these charges pushes some of these charges toward the edges, resulting in large charge density at the edges. These charges are soure of fringing fields and radiation shown in Fig 2.7. The fringing fields and the radiated power can be increased by using thicker substrate with lower value of dielectric constant [3].



Figure 2.7. Field lines.

2.9Feeding Methods.

Four fundamental techniques to feed or excite a microstrip patch antenna include edge (Microstrip Line) fed, probe fed, aperture coupled, and proximity coupled. These can be further simplified into direct (edge and probe) and noncontact (aperture and proximity-coupled) methods. Some new excitation techniques are being developed, such as the L-shape probe.

A feed line used to excite to radiate by direct or indirect contact, excited directly either by a coaxial probe or by a microstrip line. It can also be excited indirectly using electromagnetic coupling or aperture coupling and a coplanar waveguide feed, in which case there is no direct metallic contact between the feed line and the patch. Feeding technique influences the input impedance and characteristics of the antenna, and is an important design parameter. Because of the antenna is radiating from one side of the substrate, so it is easy to feed it from the other side (the ground plane), or from the side of the element [16].

The designer can build an antenna with good characteristics and good radiation parameter and high efficiency but when feeding is bad, the total efficiency could be reduced to a low level that makes the whole system to be rejected. So many good designs have been discarded because of their bad feeding. The properties of each feeding method are summarized below.

2.9.1 Microstrip Line Feeding

Microstrip line feed is one of the easier methods to fabricate if electrically thin material is used, it is a just conducting strip connecting to the patch and therefore can be consider as extension of patch. Also it is simple to model and easy to match by controlling the inset position, as shown in Figure 2.8.



Figure 2.8. Microstrip Line Feed

The disadvantage of this method is that as substrate thickness increases, surface wave and spurious feed radiation increases, which limit the bandwidth, and it also leads to undesired cross-polarized radiation [17].

This method of feeding is very widely used because it is very simple to design and analyze and very easy to manufacture. Figure 2.9 (a), (b), (c), (d) shows a patch with microstrip line feed from the side of the patch, a conducting strip is much smaller width compared to the patch.





• Quarter-wave Match Feed :

The rectangular patch antenna is approximately a one-half wavelength long section of rectangular microstrip transmission line. When air is the antenna substrate, the length of the rectangular microstrip antenna is approximately one-half of a free-space wavelength. As the antenna is loaded with a dielectric as its substrate, the length of the antenna decreases as the relative dielectric constant of the substrate increases. The resonant length of the antenna is slightly shorter because of the extended electric "fringing fields" which increase the electrical length of the antenna slightly.

• Inset feed:

The patch antenna was fed by a microstrip transmission line at the as shown in figure 2.9 (a). This typically yields a high input impedance, so we would like to modify the feed. Since the current is low at the ends of a half-wave patch and increases in magnitude toward the center, the input impedance (Z) could be reduced if the patch was fed closer to the center. One method of doing this is by using an inset feed as shown in figure 2.9 (b).

2.9.2 Coaxial Feeding.

Coaxial feeding is feeding method in which that the inner conductor of the coaxial is attached to the radiation patch of the antenna while the outer conductor is connected to the ground plane. As seen from Fig 2.10.



Figure 2.10. Probe fed Rectangular Microstrip Patch Antenna.

The main advantage of this type of feeding technique is that the feed can be plac at any desired location inside the patch in order to match with its input impedance. This kind of feed

arrangement have many advantages that it is easy to fabricate, and has low spurious radiation. However, a major disadvantage is that it provides narrow bandwidth and is difficult to model specially for thick substrate since a hole has to be drill in the substrate and the connector protrudes outside the ground plane. In addition, for thicker substrates, the increased probe length makes the input impedance more inductive, leading to matching problems. It has seen above that for a thick dielectric substrate, which provides broad bandwidth [16].

For thick substrates, which are generally employing to achieve broad BW, both the above methods of direct feeding the microstrip antenna have problems. In the case of a coaxial feed, increased probe length makes the input impedance more inductive, leading to the matching problem. For the microstrip feed, an increase in the substrate thickness increases its width, which in turn increases the undesired feed radiation. The indirect feed, discussed below, solves these problems [17].

2.9.3 Aperture Coupling:

Aperture coupling consist of two different substrate separated by a ground plane. On the bottom side of lower substrate there is a microstrip feed line whose energy is coupled to the patch through a slot on the ground plane separating two substrates as shown in figure 2.11.



Figure 2.11. Aperture-coupled feed.

This arrangement allows independent optimization of the feed mechanism and the radiating element. Normally top substrate uses a thick low dielectric constant substrate while the bottom substrate is the high dielectric substrate. The ground plane, which is in the middle,

isolates the feed from radiation element and minimizes interference of spurious radiation for pattern formation and polarization purity. The coupling aperture is usually centered under the patch, leading to lower cross polarization due to symmetry of the configuration [3].

The amount of coupling from the feed line to the patch is determined by the shape, size and location of the aperture. Since the ground plane separates the patch and the feed line, spurious radiation is minimized.

The major disadvantage of this feed technique is that it is difficult to fabricate due to multiple layers, which also increases the antenna thickness. This feeding scheme also provides narrow bandwidth.

2.9.4 Proximity Coupling.

In our research we will use this type of feed, It is also called as the electromagnetic coupling scheme, two dielectric substrates are used such that the feed line is between the two substrates and the radiating patch is on top of the upper substrate, as shown in Figure 2.12.



Figure 2.12. Proximity-coupled Feed

It has the largest bandwidth, due to overall increase in the thickness of the microstrip patch antenna, also it eliminates spurious feed radiation, and this scheme also provides choices between two different dielectric media, one for the patch and one for the feed line to optimize the individual performances, for increasing the bandwidth and directivity we should use the multilayer proximity coupled antenna [11]. Matching can be achieved by controlling the length of the feed line and the width-to line ratio of the patch. The major disadvantage of this feed scheme is that it is difficult to fabricate because of the two dielectric layers, which need proper alignment. In addition, there is an increase in the overall thickness of the antenna [15].

2.10 Methods of Analysis

There are many methods of analysis for microstrip antennas. The most popular models are the transmission-line, cavity and full-wave. The transmission-line model is the easiest of all, it gives good insight and it is adequate for most engineering purposes and requires less computation. However, it is less accurate and it is more difficult to model coupling. Comparing with the transmission-line model, the cavity model is more accurate but at the same time more complex. However, it also gives good physical insight, and is rather difficult to model coupling, although it has been used successfully. In general, when applied properly, the full-wave models are very accurate, very versatile, and can treat single elements, finite and infinite arrays, stacked elements, arbitrary shaped elements, and coupling. However, they are the most complex models and usually give less physical insight. [3].

2.10.1Cavity Model:

In this model, the interior region of the dielectric substrate modeled as a cavity bounded by electric walls on the top and bottom. The basis for this assumption is the following observations for thin substrates ($h << \lambda$). Since the substrate is thin, the fields in the interior region do not vary much in the *z* direction, i.e. normal to the patch. The electric field is *z* directed only, and the magnetic field has only t transverse components H_x and H_y in the region bounded by the patch metallization and the ground plane. This observation provides for the electric walls at the top and the bottom.



Figure 2.13. Charge distribution and current density creation on the patch

Consider Figure 2.13 shown above. When the microstrip patch provided power, a charge distribution is seen on the upper and lower surfaces of the patch and at the bottom of the ground plane .This charge distribution controlled by two mechanisms unattractive mechanisms and a repulsive mechanism as discussed by Richards. The attractive mechanism is between the opposite charges on the bottom side of the patch and the ground plane, which helps in keeping the charge concentration intact at the bottom of the patch. The repulsive mechanism is between the like charges on the bottom surface of the patch, which causes pushing of some charges from the bottom, to the top of the patch. Because of this charge movement, currents flow at the top and bottom surface of the patch. The cavity model assumes that height to width ratio (i.e. height of substrate and width of the patch) is very small and because of this, the attractive mechanism dominates and causes most of the charge concentration and the current to be below the patch surface. Much less current would flow on the top surface patch and as the height to width ratio further decreases, the current on the top surface of the patch would be almost equal to zero, which would not allow the creation of any tangential magnetic field components to the patch edges. Hence, the four sidewalls could be modeled as perfectly magnetic conducting surfaces. This implies that the magnetic fields and the electric field distribution beneath the patch would not be disturbed [3].

2.10.2 Transmission line Model.

For the design of this project, the transmission-line model is selected as it provides is reasonable interpretation of the radiation mechanism while simultaneously giving simple expressions for the characteristics. In this model, a rectangular microstrip antenna is represented as an array of two radiating narrow aperture (slots), each of width *W* and height *h*, separated by a low impedance *ZC* transmission line of length *L*.

In the Figure 2.14 shown below, the microstrip patch antenna is represented by two slots separated by a transmission line of length L and open circuited at both the ends. Along the width of the patch, the voltage is maximum and current is minimum due to the open ends. The fields at the edges can be resolved into normal and tangential components with respect to the ground plane.



Figure 2.14.a Top View of Antenna Figure

2.14.b Side View of Antenna

• The patch:

In order to operate in the fundamental mode, the length of the patch must be slightly less than $\lambda/2$ where λ is the wavelength in the dielectric medium and is equal to $\lambda_0/\sqrt{E_r eff}$ where λ_0 is the free space wavelength. This mode implies that the field varies one $\lambda/2$ cycle along the length, and there is no variation along the width of the patch. [11].

Because the electric field lines are moving into the air before entering the dielectric substrate as shown in figure 2.15, the ε r will be replaced by ε reff which is slightly less than ε r.



Figure 2.15. Electric field lines in a transmission line.

The equation of Ereff is given by:

$$\mathcal{E}reff = \frac{\mathcal{E}r}{2} + \frac{\mathcal{E}r+1}{2} * \left[1 + 12 * h/W\right]^{-0.5}$$
(2.5)

Where,

- ϵr = The dielectric constant of the substrate.
- h = The height of the dielectric substrate.

W = The width of the patch.

Because the electric field line move through the air, the length of the patch is extended on both sides. Figure 2.14 (a) shows the two radiating slots along the length of the patch.

Looking at figure 2.14 (b) the electric field lines at the two edges of the width are in opposite directions (E_V). They are out of phase and thereby cancel each other out. The two components which are in phase (E_H), give the maximum radiated field by combining the resulting fields. It is said that the radiation is produced by these two radiation slots.

The extended length ΔL can be calculated by the following equation:

$$\Delta L= 0.0412 h \frac{(\epsilon_{reff}+.03)(W/h+0.264)}{0.0412 h (\epsilon_{r}+.03)(W/h+0.264)} \dots (2.6)$$

Thus, the width is extended too; there are no reason in calculating the extension because the electric fields cancel each other out.

The width W can be calculated by using equation (2.4)

The effective length Leff can be calculated by the following equation:

$$l_{eff} = \frac{c}{2 f_0 \sqrt{\epsilon_{\text{reff}}}} \qquad (2.7)$$

Then the actual length of my patch can be calculated by the using equation (2.2).

• Ground planes:

Essentially the transmission line model is applicable to an infinite ground plane only. However, it has been shown that a finite ground plane can be used for if the ground plane is 6 times larger than the height of the dielectric substrate plus the used length or width. The ground plane can now be calculated as: ground plane can now be calculated as:

Wg = 6 * h + W	 (2.8)
Lg = 6 * h + L	 (2.9)

• Edge feed rectangular microstrip patch antenna:

The microstrip antenna can also be matched to a transmission line of characteristic impedance *Z*0 by using a quarter-wavelength transmission line of characteristic impedance Z1 as shown in Figure 2.16.



Figure 2.16. Patch antenna with a quarter-wavelength.

The goal is to match the input impedance (Zin) to the transmission line (Z0). If the impedance of the antenna is Za, then the input impedance viewed from the beginning of the quarter-wavelength line becomes

$$Zin\left(l=\frac{\lambda}{4}\right) = \frac{Zo^2}{ZA} \qquad (2.10)$$

Where,

Zin: the input impedance.

l: the transmission length.

 λ : wavelength.

 $Zo^{=\sqrt{\frac{\mu 0}{\epsilon_0}}}$: the is free space impedance.

E0: permittivity of free space.

μ0: permeability of free space.

ZA: the impedance of the load.

This input impedance Zin can be altered by selection of the Z1, so that Zin=Z0 and the antenna is impedance matched. The parameter Z1 can be altered by changing the width of the quarter-wavelength strip. The wider the strip is, the lower the characteristic impedance (Z0) is for that section of line.Because the quarter-wavelength transmission line is only a quarter-wavelength at a single frequency; this is a narrow-band matching technique.





The impedance of the patch is given by (2.11):

$$Za = 90\left(\frac{\varepsilon r^2}{\varepsilon r^{-1}}\right) \left(\frac{L}{W}\right)^2 \dots (2.11)$$

Where,

Za: impedance of the patch.

Er: dielectric constant.

L: the length of the rectangular patch.

W: the width of the rectangular patch.

The characteristic impedance of the transition section should be:

 $Zt = \sqrt{Za * Zo} \qquad (2.12)$

Where,

Zt: characteristic impedance of the transition section.

The width of the transition line is calculated from (2.13):

$$Zt = \frac{60 \quad (\ln(\frac{8d}{Wt} + \frac{Wt}{4d}))}{\sqrt{\varepsilon r}} \tag{2.13}$$

Where,

Wt: the width of the transition line

The width of the $Zo\Omega$ microstrip feed can be found using the equation (2.14) below:

$$Zo = \frac{120\pi}{\sqrt{\varepsilon reff} \left(1.393 + \frac{W}{h} + \frac{2\ln\left(\frac{W}{h} + 1.444\right)}{3} \right)}$$
(2.14)

Where,

Ereff: the effective dielectric constant.

h: the height of the dielectric.

The length of the strip can be found from (2.15):

$$Rin(x = 0) = \cos\left(\frac{\pi}{L} xo\right)^2$$
 (2.15)

Where,

x0: the feed length at distance equals zero.

The length of the transition line is quarter the wavelength:

$$l = \frac{\lambda}{4} = \frac{\lambda 0}{4\sqrt{\varepsilon reff}}$$
 (2.16)

Where,

l: the length of the transition line.

 $\lambda 0$: the free space wavelength.

• inset feed rectangular microstrip patch antenna:

Equation (2.17) has been formulated for the resonant frequency, which depends on notch width.

$$fr = \frac{Vo*4.6*10^{-14}}{g*\sqrt{2*Ereff}} + \frac{f}{1.01}$$
(2.17)

Where,

*f*r: for the resonant frequency.

Vo: velocity of electromagnetic wave.

g: notch width.

Ereff: effective dielectric constant.

f: Operating frequency in GHz.

The design procedure assumes that the specified information includes the dielectric constant of the substrate (Er) and the height of the substrate (h) and is stated as below:

1. Specify the center frequency and select a substrate permittivity (Er) and a substrate thickness (h).

 $h \ge 0.06 \ \frac{\lambda a i r}{\sqrt{\varepsilon r}} \tag{2.18}$

- 2. Calculate patch width by using eqn. (2.4)
- 3. Calculate $\mathcal{E}r$ by using eqn. (2.5), for w/h>1.
- 4. ΔL is the normalized extension of the length and given as shown in eqn. (2.6).
- 5. Calculate the length of the patch L and Zo by using eqn. (2.2).
- 6. Calculate the notch width, g by using eqn. (2.19). To obtain the desired resonance fr at the operating f i.e. fr=.

$$f = \frac{V_{0*4.6*10^{-14}}}{g_*\sqrt{2*Ereff}} + \frac{f}{1.01}$$
(2.19)

7. Calculate the value of Zo as:

$$Zo = Rin \cos\left(\frac{\pi}{L}d\right)^2 \qquad (2.20)$$

Where,

Rin: is the resonant input resistance when the patch is fed at a radiating edge.

d: the inset distance from the radiating edge.

• The resonance input resistance in *R*in calculation:

A rectangular microstrip patch can be represented as an array of two radiating slots, each of width W, height h and separated by a distance L. Each slot is equivalent to a parallel equivalent admittance Y with conductance G and susceptance B. The equivalent circuit transmission model of a microstrip patch antenna.

The conductance of a single slot can be obtained using the following equation:

$$G1 = \frac{1}{120\pi^2} \int_0^{\pi} \left[\frac{\sin\left(\frac{kW}{2}\cos\theta\right)}{\cos\theta} \right]^2 \sin\theta^{3\,d\theta} \quad \dots \tag{2.21}$$

The mutual conductance G12 can be calculated using (2.22):

$$G12 = \frac{1}{120\pi^2} \int_0^{\pi} \left[\frac{\sin\left(\frac{kW}{2}\cos\theta\right)}{\cos\theta} \right]^2 * \int_0^{\infty} (kL\sin\theta) \sin\theta^3 d\theta \quad \dots \tag{2.22}$$

Where,

J: the Bessel function of the first kind of order zero.

The mutual conductance obtained using equation (2.21) is small compared to the self conductance. Taking mutual effects into account between the slots, the resonant input impedance can be calculated as (2.23).

$$Rin = \frac{1}{2*(G1+G12)}$$
 (2.23)

The total admittance at slot number 1 is obtained by transferring the admittance of slot number 2 from the output terminals to input terminals using the admittance transformation equation of transmission line. The separation of the two slots is slightly less than $\lambda/2$, thus the transformed admittance of slot number2 becomes (2.24).

Y=G2 +JB2 = G1- JB1	 (2.24)
	<u>, - · - ·</u>	,

Where,

Y : is an admittance.

G2: is conductance and susceptance B.

Therefore, the total resonant input admittance is real and is given by:

Y = Y1 + Y2 = 2 G1	.25	5)
--------------------	-----	----

The total input impedance is also real:

Zin = 1/Yin = Rin = 1/(2 G1) (2.26)

The resonant frequency is given by:

$$f_r = \frac{c}{2L\sqrt{\epsilon_{\text{reff}}}} = q \frac{c}{2L\sqrt{\epsilon_{\text{reff}}}} \qquad (2.27)$$

Where,

q: is the fringe factor.

Chapter 3

Software Design

- 3.1 Ansoft Designer software.
- 3.2 Designing microstrip transmission line.
- 3.3 Designing printed dipole antenna.
- 3.4 Designing rectangular patch with feed line.
- 3.5 project's FLOW CHART.

Chapter Three

Software Design

3.1 Ansoft Designer Software:

Ansoft Designer is an integrated schematic and design management front-end for Ansoft's best-in-class simulation technologies. Ansoft Designer is the foundation for a highly accurate design flow that allows users to precisely model and simulate complex analog, RF, and mixed-signal applications and perform signal-integrity analysis and system verification of highperformance IC/package/board designs. This flexible, easy-to-use software includes schematic capture and layout editing, net list generation and sophisticated data visualization and analysis tools.

This dynamic, parameterized co-simulation capability allows engineers to autointeractively achieve optimal designs. Integration is achieved not through a rigid top-down hierarchy which limit designers, but through powerful handshaking mechanisms that empower individual designers to apply their creativity and skill to develop high-performance and costeffective solutions.

For high-performance RF/mW design, Ansoft Designer combines system-level behavioral base-band and RF blocks with transistor level detail for analog circuits and 3D full-wave electromagnetic detail at the component level to provide accurate board-level simulations of EVM, BER, ACPR, IP3, and PAE.

For high-performance analog/RFIC verification, Ansoft Designer complements existing IC design capture and advanced package layout tools with its built-in planar electromagnetic solvers and dynamic, parameterized co-simulation with HFSS and Nexxim. Engineers can create accurate models of on-chip passives and board/package interconnects, combine them with detailed analog circuits and simulate the true interactions between active non-linear devices and passive parasitics at high frequencies.

Analysis:

- Linear Circuit Simulation: including S, Y and Z parameters and VSWR, insertion/return loss, gain, stability, noise figure and group delay
- Filter Synthesis
- Transmission Line Synthesis
- Planar Electromagnetics: including Near and Far Field Radiation

Features:

- Easy-to-use Graphical User Interface (GUI)
- Fully integrated schematic and layout editors
- Component library developer and manager
- Vendor component models
- 3D post-processing and results viewer
- S-parameter import
- Smith too

3.2 Designing a transmission line using Ansoft Designer Software:

Ansoft Designer is a microwave engineering CAD suite that allows for circuit and full-wave simulation. In this design, a microstrip transmission line is simulated with Designer. The basic model of a microstrip transmission line is shown in Fig.3.2.1. The microstrip line will be designed on a substrate with a dielectric constant of 10.2 and a height of 1.27 mm at 5.0 GHz; the width of the microstrip is designed for 50 Ω and the length for a 180 degree phase delay.





The methods used to setup the simulation are outlined. In particular, the following topics are covered:

- Planar EM Design Setup in Designer.
- Model Setup.
- Excitation Setup.
- Analysis Setup.
- Plotting Results.

3.2.1Planar EM Design Setup in Designer:

First load up Ansoft Designer, then go to Project > Insert Planar EM Design to launch the MOM simulator. A window will appear asking you to choose a layout technology (substrate) as shown in Fig. 3.2.2. Pick MS - RT _ duroid 6010 with a height of 0.010 inch.



Figure 3.2.2. Choose layout technology window.

Once, you have chosen the technology, a project window will appear. Before we can setup the model, we need to correct the substrate height. To do this, go to Layout > Layouts and the Edit Layers window will appear as shown in Fig. 3.2.3 Change the thickness of the dielectric to 1.27 mm and the trace to 0 mm. If you like to save the substrate for future use, click on File > Save As Technology File and next time you insert a new planar EM design, you can select the same substrate.

	Name	Туре	Material	Drag Mo	Thickn	Lower Elevati	Upper Elevati	Roughn
E	Trace	signal	copper	middle al	Omm	50mil	50mil	Omil
	Diele	dielectric	Rogers RT/duroid 6010/6010LM		1.27mm	Omil	50mil	
-	Ground	metalizedsi	copper	middle al	Omil	Omil	Omil	Omil

Figure 3.2.3. Layers dialog box.

3.2.2 Model Setup:

You are now ready to draw the microstrip line trace. Before doing so, the width and length have to be determined. Using the microstrip line calculatoras shown in figure 4.1, a width of 1.19 mm and a length of 11.47 mm is needed to realize a 50 Ω with a 180 degree phase delay at 5.0 GHz.

Microstrip Line Calculator

		conductor
Maxwell Ultracapacitors www.richardson Buy Now! BOOSTCAP® Cells & Modules Worldwide, Design Support	nfpd.com 3 In Stock	W L
Warehouse Simulation www.cirruslogistic The Class warehouse design and simul Cirrus Logistics	<u>cs.com/class/</u> lation tool by	h dielectric (ε_r)
Gaussmeter RF & EMF-Meter www.aaro HighEnd Analyzer at low-cost even sho Frequency, Power and Limits!	mia.com W	ground © emtalk.com
Polymorph Screening www.solidformsolu characterisation, polymorphism, amorp compounds, crystallisatio	utions.co.uk hous	Dielectric Constant (ε _r): 10.2
	AdChoices ▷	Dielectric Height (h): 1.27 mm -
		Frequency: 5 GHz
Electrical Parameters		Physical Parameters
Zo: 50	Ω	hesize Width (W): 1.19133400752 mm 💌
Elec. Length: 180	deg Ana	alyze Length (L): 11.4719437676 mm 💌

Figure 3.2.4. Microstrip line calculator.

To draw the trace, click on the rectangle tool or go to *Draw > Primitive > Rectangle*. Just draw any size rectangle for now. After it is drawn, double-click on it and the dialog box will appear; fill in with the values shown in Fig. 4.2 Save the project before continuing if you have not already done so.

	Name	Value	Unit	Evaluated Value	Description
	Туре	rect			
	Name	rect_1			
	PlacementLayer	Trace			
	Net				
L	LineWidth	0	mm	Omm	
	2 pt Description	v			
	Pt A	-5.735 , -0.595	mm	-5.735mm , -0.595mm	
	Pt B	5.735, 0.595	mm	5.735mm , 0.595mm	
	Angle	0	deg	Odeg	

Figure 3.2.5. Rectangle dialog box.

3.2.3 Excitation Setup:

The excitation ports for the microstrip line have to be setup. To do this, go to Edit > Select Edge and select the left edge of the microstrip line. Then assign a port by clicking on Draw >EdgePort. Do the same for the right edge. Make sure to make the ports Edge Ports and not Gap Sources, by going to Planar EM > Port Excitations and unchecking the Gap Source box. The completed microstrip line model should look like Fig. 3.2.6.



Figure 3.2.6. Completed microstrip transmission line drawn in Ansoft Designer.



Figure.3.2.7. 3-D view of completed microstrip transmission line drawn in Ansoft Designer.

3.2.4 Analysis Setup:

To setup the analysis, go to *Planar EM > Solution Setup > Add Solution Setup*. Since this is a geometrically simple structure, a fixed mesh will give an accurate result. Use a fixed mesh with a frequency of 10.0 GHz as shown in Figure 3.2.8.

Setup 3	×
Meshing Parameters Mesh Refinement	
Initial Mesh	
Fixed Mesh Frequency	10.0000GHz
Use Edge Mesh	
Edge mesh length ratio	0.1
C Absolute edge length	1000.0000mm
Include edges from layers closer than	0.0000meter
C Do Adaptive	
Adaptive Parameters	
Maximum Number of Adaptive Passes	10
Adaptive Frequency:	5.0000GHz
Percent Refinement Per Pass:	25
Target Maximum Delta S	0.05
Mesh Display Attributes	
Color	
Reset to Suggested Val	ues
	OK Cancel

Figure 3.2.8. Fixed mesh with a frequency of 10.0 GHz.

In addition, add a frequency sweep from 2.0 GHz to 8.0 GHz by going to *Planar EM* > *Solution Setup* > *Add Frequency Sweep*; do an interpolating sweep from 2.0 GHz to 8.0 GHz with 201 points as shown in figure 3.2.9.Next, analyze the problem.

Sweep 2	
Type Discrete Generate Surface Current Interpolating Specify Frequency Sweep Single value Linear step Linear count Decade count Start: Stop: 8 GHz Count Stop: Start: Stop: Stop: Start: Stop:	Sweep Description Linear Count from 2GHz to 8GHz, count=201 Add >> Update >> Delete
Setup Full Wave Spice	View Sweep Points List OK Cancel

Figure 3.2.9 Frequency sweep window.

3.2.5 Plotting Results:

After the simulation is finish, we can confirm that the characteristic impedance is 50.345 Ω and has a S₂₁ phase of 176 degrees by going to Planar EM > Results > View Profile and looking at the matrix data at 5.0 GHz. Fig.3.2.10 shows the profile window with matrix data at 5.0 GHz.

💩 Solutio	ns: Pro	oject1 - Plan	arEM1	L					
Design Var Simulation: Matrix (iation: Conver	Setup 2	le	▼ S	weep 1	¥			 ✓
I⊽ SM I∏ YM I∏ ZM	atrix atrix atrix	Gamma ✔ Z0	Magn	itude/Phase Freqs. Iz)		•	Equiva	Export	Export
Freq		S:Port	1	S:Port	2	Por	t Z0		
5 (GHz)	Port1 Port2	(0.021697, (0.93818,	-9.88) 172)	(0.93818, (0.021699,	172) -9.88)	(50.34 (50.34	5, O) 5, O)		
				Cl	ose				

Figure 3.2.10 Matrix data dialog box.

Next, a S-parameter magnitude plot is created showing the return and insertion loss of the microstrip line by Planar EM > Results > Create Report and plotting S11 and S21 as shown in Figure 3.2.11.

Traces X	Y	Y-a	xis Add BlankTrace
			Remove Trace
Context Design: PlanarEM1	Sweeps X Y	Quantity:	Function:
Solution: Setup 2 : Sweep 1	Variables Output Variables S Parameter Y Parameter Z Parameter Gamma Port Zo	S(Port1, Port1) S(Port1, Port2) VSWR(Port1) S(Port2, Port1) S(Port2, Port2) VSWR(Port2)	ang ang_rad dB im mag re
Output Variables		AddTuse	T.m. 1
Apply	Done	Add Trace Replace	Trace

Figure 3.2.11 plotting S11 and S21.



The resulting plot is shown in Fig. 3.2.12 which shows the microstrip line is broadband.

Figure 3.2.12. Numerical return and insertion loss.

3.3 Printed dipole antenna (differential feed)

In this application a printed dipole antenna with a differential feed is modeled and simulated in Ansoft Designer. The printed dipole antenna is often used in planar microwave radiative applications that require an omni-directional pattern. The model of the printed dipole is shown in Fig3.3.1. The dipole arm's width (W) and length (L) will be optimized for 3.0 GHz operation, while the feed gap (g) and the substrate height (h) will be fixed. The model and simulation setup are outlined.



Figure 3.3.1. Model of printed dipole antenna based on differential feeding.

3.3.1 layers setup

First load up Ansoft Designer, then go to *Project > Insert Planar EM Design* to launch the MOM simulator. A window will appear asking you to choose a layout technology (substrate) as shown in Fig. 3.3.2. Pick *MS - RT_duroid 5880* with a height of 0.010 inch. Once, you have chosen the technology, a project window will appear. Before we can setup the model, we need to remove the ground plane. To do this, go to *Layout > Layouts* and the *Edit Layers* window will appear. Select the ground layer and then click on *Remove Layer*. The Edit Layer window should look like Fig. 3.3.3, when the ground later is removed.



Figure 3.3.2. Choose layout technology window.

2	-	5	Meanures	Table (PA	Calor	Pasem	cether .
õ	1	1	Rats	rat			nether
C	1	1	Eros	entor			nether
C	-	-	Symbols	symbol		600000000000000000000000000000000000000	neither
C	1	1	Assembly	assembly			top
C	•	$\overline{\mathbf{v}}$	Sikacreen	sikacreen		17////////	top
C	1	1	Trace	signal			nether
0		1	Dielectric	delectric			nether
56 La	yer	1	Remove Layer]			

Figure 3.3.3 Layers dialog box.

3.3.2Model setup:

We are now ready to start drawing the printed dipole. Before doing so, we first need to estimate what the length of the dipole should be. Since we are interested in the first resonance, a half-wavelength dipole will be designed. Therefore, the length of each arm should be around a quarter wavelength at 3.0 GHz. At 3.0 GHz, the free space wavelength is 100 mm, therefore each dipole arm will be 25 mm long. The width of the dipole arms will be set to 5 mm and the gap between the two arms will be set to 1 mm. Since, the electric field will fringe at the end of the dipole arms, the actual length of the dipole should be a little shorter than a half-wavelength. As a result, the dipole model will be parameterized; the arm length (L), arm width (W), and the gap (g) will be set as variables.

The first dipole arm will be drawn. First select the rectangle tool and just draw a random rectangle. Next, double click on the rectangle and for *Pt*. *A* enter -g/2, -W/2 and for *Pt*. *B* enter -L/2-g/2, W/2. A dialog box asking for the value of each variable will appear, enter the following for each:

- g: 1 mm
- W: 5 mm
- L: 50 mm

For the other dipole arm, g/2,-W/2 for *Pt.A* and *Pt. B* to g/2 and L/2+g/2 as shown in Fig.3.3.4. Your completed geometry should look like Fig.3.3.5.
Nan	ne	Value	Unit	Evaluated Value	Description
Туре	rect				
Name	rect_1				
Placement	ayer Trace				
Net	****				
LineWidth	0		mm	Omm	
2 pt Descrip	tion	v			
Pt A	-0.5 , -2.5		mm	-0.5mm , -2.5mm	
Pt B	-25.5 , 2.5		mm	-25.5mm , 2.5mm	
Angle	-0		deg	-Odeg	
					Show Hidden

Figure 3.3.4. A dialog box.





3.3.3 Excitation setup:

A differential excitation has to be applied in the gap separating the two dipole arms. To setup the excitation port, go to *Edit > Select Edges* and select the gap edge of the first drawn dipole arm as shown in Fig. 3.3.6.

💵 Project10 - PlanarEM1 - Layout	- • •
< III	►

Figure.3.3.6. Selected edge for port definition



Figure 3.3.7. Add port.

Next, assign an edge port to the selected edge by going to *Draw* >*Edgeport*. The completed port needs a reference in order to be defined correctly since there is no ground plane. The edge of the other dipole arm will be used as the reference to create a differential port. To create the differitial port, select the other dipole arm's gap edge and go to the port definition in the project tree, right-click on the port, and then select *Add Reference* as shown in Fig. 3.3.8.



Figure 3.3.8. Differential port setup.

3.3.4 Analysis setup:

To setup the analysis, go to *Planar EM > Solution Setup > Add Solution Setup*. Since this is a geometrically simple structure, a fixed mesh will give an accurate result. Use a fixed mesh with a frequency of 4.0 GHz as shown in Fig 3.3.9. In addition, add a frequency sweep from 2.0 GHz to 4.0 GHz by going to *Planar EM > Solution Setup > Add Frequency Sweep*; do an interpolating sweep from 2.0 GHz to 4.0 GHz with 201 points as shown in Fig 3.3.10. Next, analyze the problem.

- Initial Mesh	ennement		
Fixed Mesh	Frequency	40000GHz	
Use Edge Mesh			
🕥 Edge mesh	length ratio	0.1	
C Absolute ed	ge length	1000.0000mm	
Include edges from layer	s closer than	0.0000meter	
C Do Adaptive			
Adaptive Parameters			
Maximum Number of Ada	aptive Passes	10	
Adaptive Frequency:		5.0000GHz	
Percent Refinement Per	Pass:	25	
Target Maximum Delta S	•	0.05	
Mesh Display Attributes			
Color			
Rese	t to Suggested Val	Jes	
		ОК	Cancel

Fig 3.3.9.Fixed mesh with a frequency of 4.0 GHz.

Discrete		Sweep Description	
Generate Surface Current		Linear Count from 2GHz to 4GHz, count=201	
C Interpolating			
Specify Frequency Sweep			
Single value			
C Linear step			
• Linear count	Add >>		
C Decade count			
Start: 2 GHz 💌	Update >>		
Stop: 4 GHz 💌			
C 1 201	Delete		
Count: [201			

Fig 3.3.10. Frequency sweep window.

3.3.5 Plotting results:

After the simulation is finish, we can plot the real and imaginary parts of the input impedance over the 2.0 Ghz to 4.0 GHz range to confirm the resonant frequency. Fig.3.3.11. shows the resulting input impedance; the results show that the dipole resonants at 2.75 GHz (Imag(Zin)=0).



Figure 3.3.11. Input impedance of un-optimized printed dipole.



Figure 3.3.12. Radiation Pattern.

3.4 Designing Rectangular Microstrip Patch Antenna with Feed line using Designer.

The rectangular microstrip patch as shown in figure 1 will be designed on a substrate with a dielectric constant of 2.2 and a height of 1.58 mm at 2.4 GHz; the width of the rectangular microstrip patch is designed for 50 Ω and the length for a 180 degree phase delay. The methods used to setup the simulation are outlined. In particular, the following topics are covered:

- Layers Setup.
- Model Setup.
- Excitation Setup.
- Analysis Setup.
- Plotting Results.



Figure 3.4.1. Rectangular Microstrip Patch Antenna.

3.4.1 Layers Setup

Open Ansoft Designer, then Project > Insert Planar EM Design > none as shown in Figure 3.4.2, then to add layers go to Layout > Layers ... Stackup taband add the following layers:

- Add Layer > Name: ground, Type: metalizedsignal
- Add Layer > Name: rogers, Type: dielectric change thickness to "1.58mm". The material should be: "Rogers RT/duroid 5880 (tm)" with εr = 2.2
- Add Layer > Name: signal, Type: signal.

Figure 3.3.3 shows Layers dialog box with three layers the signal, rogers and the ground layer.

Choose Layout Technology	
$\label{eq:ms} \begin{array}{l} MS \cdot Alumina \ (Er = 9.8) \ 0.010 \ inch, \ gold \\ MS \cdot Alumina \ (Er = 9.8) \ 0.025 \ inch, \ gold \\ MS \cdot FR4 \ (Er = 4.4) \ 0.030 \ inch, \ 0.5 \ oz \ copper \\ MS \cdot FR4 \ (Er = 4.4) \ 0.060 \ inch, \ 0.5 \ oz \ copper \\ MS \cdot FR4 \ (Er = 4.4) \ 0.060 \ inch, \ 0.5 \ oz \ copper \\ MS \cdot RT_duroid \ 5880 \ (Er = 2.20) \ 0.010 \ inch, \ 0.5 \ oz \ copper \\ MS \cdot RT_duroid \ 5880 \ (Er = 2.20) \ 0.020 \ inch, \ 0.5 \ oz \ copper \\ MS \cdot RT_duroid \ 5880 \ (Er = 2.20) \ 0.020 \ inch, \ 0.5 \ oz \ copper \\ MS \cdot RT_duroid \ 6010 \ (Er = 10.2) \ 0.010 \ inch, \ 0.5 \ oz \ copper \\ MS \cdot RT_duroid \ 6010 \ (Er = 10.2) \ 0.025 \ inch, \ 0.5 \ oz \ copper \\ PCB \cdot DoubleSided \\ PCB \cdot SingleSided \\ SL \cdot Alumina \ (Er = 9.8) \ 0.010 \ inch, \ gold \\ SL \cdot Alumina \ (Er = 9.8) \ 0.025 \ inch, \ 0.5 \ oz \ copper \\ SL \cdot FR4 \ (Er = 4.4) \ 0.030 \ inch, \ 0.5 \ oz \ copper \\ SL \cdot FR4 \ (Er = 4.4) \ 0.060 \ inch, \ 0.5 \ oz \ copper \\ SL \cdot FR4 \ (Er = 4.4) \ 0.060 \ inch, \ 0.5 \ oz \ copper \\ SL \cdot FR4 \ (Er = 4.4) \ 0.060 \ inch, \ 0.5 \ oz \ copper \\ SL \cdot FR4 \ (Er = 4.4) \ 0.060 \ inch, \ 0.5 \ oz \ copper \\ SL \cdot FR4 \ (Er = 4.4) \ 0.060 \ inch, \ 0.5 \ oz \ copper \\ SL \cdot FR4 \ (Er = 4.4) \ 0.060 \ inch, \ 0.5 \ oz \ copper \\ SL \cdot FR4 \ (Er = 4.4) \ 0.060 \ inch, \ 0.5 \ oz \ copper \ oupper \ Oupper$	
SL - RT_duroid 5880 (Er=2.20) 0.010 inch, 0.5 oz copper SL - RT_duroid 5880 (Er=2.20) 0.020 inch, 0.5 oz copper SL - RT_duroid 6010 (Er=10.2) 0.010 inch, 0.5 oz copper Open Browse None Cancel	•



	Name	Туре	Material	Drag Mode	Thickness	Lower Elevation	Upper Elevation	Roughness	Π
	signal	signal	copper	middle align	Omm	1.58mm	1.58mm	Omm	
22	rogers	dielectric	Rogers R		1.58mm	Omm	1.58mm		
	ground	metalized	copper	middle align	Omm	Omm	Omm	Omm	
		-1		- 1					



3.4.2 Model setup

Calculate the lengths and widths necessary for the patch antenna using the Transmission line Mode we get the patch dimensions (width, length) = (41.334, 49.4) mm.Use Ansoft designer to calculate the length and width of the 50 ohm feedline to the patch. Then go to Project > Insert Circuit Design >None as shown in figure 3.4.4.



Figuer 3.4.4. Choose layout technology window.

To construct the layers go to Schematic > Layout Stackup...repeat the stackup layers to create the same stackup as in the planer EM as shown in figure 3.4.5.then go to Circuit > Add Model Data > Add Substrate Definition, in the dielectric area: H = 1.58mm, Er = 2.2 as shown in figure 3.3.6.

Then go to Circuit > TRL >Microstrip> Single, Select Substrate > OK, Set Z0 = 50, E = 180, Frequency = 2.4GHz, H = 1.58 mm (Make sure Dimension is in mm and GHz), then push synthesis then OK. Note the values of W and P for the microstrip that you have created this is the width and the length of the 50 ohm transmission line that you will create in the planar too as shown in figure 3.4.7.

Edit Laye	ers -	Circuit1								×
Layers	St	ackup								
		Name	Туре	Material	Drag Mode	Thickness	Lower Elevation	Upper Elevation	Roughness	
	_	signal	signal	copper	middle align	Omm	1.58mm	1.58mm	Omm	
		rogers	dielectric	Rogers R		1.58mm	Omm	1.58mm		
	-	ground	metalized	copper	middle align	0mm	Omm	Omm	Omm	
	A	dd I aver		Remove I	er Numbe	r of Sublavers:	1 -			
]	Ad	dd Layer		Remove Lay	er Numbe	er of Sublayers:	1 +			
	Ad	dd Layer	nsistent elev	Remove Lay	er Numbe	er of Sublayers:	1 +			
	Ac M	dd Layer	nsistent elev	Remove Lay	rdered layers	er of Sublayers:	1 <u>+</u>			

Figure 3.4.5. Layers dialog box.

Substrate Definition	
	Dielectric
Substrate Name: Substrate	H 1.58 mm 💌
Substrate Type: Microstrip	Er 2.2 TANM 0
	MRem 0
Cover → Metalization → Air Substrate Dielectric Er, TAND Magnetic MsAT	HU Select E dit
MREM Ground TANM	Material Resistivity Thickness Unit 1
	Roughness: Clear Material

Figure 3.4.6. Substrate definition box.

Microstrip single	
- Dimensions	W HU Z0 50 Dimension
P [45.3941]	P E, F ISAT, MREM, TANM E 180 Impedance
Frequency	Frequency
2.4 Analysis Auto Calculate OF	Reset All Synthesis 2.4 Electrical
H 1.58mm Er 2.2 Bot	Metal Name Code Resistivity Thickness Deg "None"
MSat 0 TANM 0 Top	None*
MRem 0 RG	0
Details>>	OK Cancel

Figure 3.4.7. Microstrip Line Calculator.

Back to your palner EM then go to Draw > Primitive > Rectangle, draw a random rectangle and this will be your patch antenna, click a double click the new rectangle and define its points, Point A should be 0,0 Point B should be L,W where L and W are the length and width that you calculated for the patch, figure 3.4.8 shows the rectangle dialog box for the patch.

Type rect Image: median state in the image: m	Type Name PlacementLayer	rect_1			
Name rect_1 Image: Signal	Name PlacementLayer	rect_1			
PlacementLayer signal Net LineWidth 0 mm 0mm 2 pt Description Image: Constraint of the second	PlacementLayer				
Net Image: Constraint of the state		signal			
LineWidth 0 mm 0mm 2 pt Description Image: Constraint of the second sec	Net				
2 pt Description Image: Constraint of the second seco	LineWidth	0	mm	Omm	
Pt A 0,0 mm 0mm,0mm Pt B 41.334,49.4 mm 41.334mm,49.4mm	2 pt Description	▼			
Pt B 41.334 , 49.4 mm 41.334mm , 49.4mm	Pt A	0.0	mm	Omm , Omm	
	Pt B	41.334 , 49.4	mm	41.334mm , 49.4mm	
Angle 0 deg -Odeg	Angle	0	deg	-Odeg	

Figure 3.4.8. Rectangle dialog box for the patch.

Then go to Draw> Primitive > Rectangle, draw a random rectangle – this will be your feedline antenna click a double click the new rectangle and define its points, Point A should be 0,0 Point B should be W,-P where W and -P are the width and length that Ansoft calculated for the feedline, figure 3.4.9 rectangle dialog box for the feed line.

Typ Na Pla	rpe ame	rect 3			
Na Pla	ame	rect 3			
Pla					
	acementLayer	signal			
Ne	et				
Lin	neWidth	0	mm	Omm	
2p	ot Description	v			
Pt	A	0.0	mm	Omm , Omm	
Pt	В	4.87445.4	mm	4.874mm , -45.4mm	
.An	igle	oľ	deg	-0deg	

Figure 3.4.9. Rrectangle dialog box for the feed line.

Note that you should make the length value negative so that the edges of your two rectangles are touching, select both rectangles, Draw > Align > Center Horizontally > OK.The Patch antenna with feed line is finished as shown in figure 3.4.10.



Figure 3.4.10. The patch antenna with feedline.

3.4.3 Excitation Setup:

The excitation ports for the microstrip feed line have to be setup. To do this, go to Edit > Select Edges, select the bottom edge of your transmission line, In the Project Window, Excitation > Add Port, figure 3.4.11 shows the edge port at the end of feed line.



Figure 3.4.11 the edge port at the end of feed line

Then Edit > Select to get back to a regular cursor, then click double click the port itself, go to the Planar EM Tab and set the "Renormalize" to 50+0i, as shown in figure 3.4.12.

Г	Name	Value	Unit	Evaluated Value	Description
	Port	Port1			
	PortSolver	~			
	Phase	0	deg	Odeg	
	Magnitude	1	mA	1mA	
	PostProcess				
	Renormalize	50 + Oi	Ohm	500hm + 0i 0hm	
	Deembed	0	mm	Omm	
	RefToGround				
	Туре	Single Strip Gap Source			

Figure 3.4.12 the load impedance on the port.

3.4.3 Analysis Setup:

To setup the analysis, go to Planar EM > Solution Setup > Add Solution Setup. Since this is a geometrically simple structure, a fixed mesh will give an accurate result. Use a fixed mesh with a frequency of 2GHz. As shown in figure 3.4.13. In addition, add a frequency sweep from 1.0 GHz to 3.0 GHz by going to Planar EM > Solution Setup > Add Frequency Sweep; do an interpolating sweep from 2.0 GHz to 3.0 GHz with 1000 points as shown in figure 3.4.15. Next, analyze the problem.

shing Parameters Mesh Refinement	
Initial Mesh	
Fixed Mesh Frequency	y 20000GHz
🔲 Use Edge Mesh	
Edge mesh length ratio	0.1
C Absolute edge length	1000.0000mm
Include edges from layers closer than	0.0000meter
C Do Adaptive	
Adaptive Parameters	
Maximum Number of Adaptive Passes	10
Adaptive Frequency:	5.0000GHz
Percent Refinement Per Pass:	25
Target Maximum Delta S	0.05
Mesh Display Attributes	
Color	
Reset to Suggested V	alues

Figure 3.4.13. Fixed mesh with a frequency of 2GHz.

Sweep 1	×
Type	Sweep Description Linear Count from 1 GHz to 3GHz, count=1000
Specify Frequency Sweep Single value Linear step Linear count	Add >>
Start: 1 GHz V Stop: 3 GHz V	Update >> Delete
Setup Full Wave Spice	View Sweep Points List OK Cancel

3.4.14. Frequency sweep window.

3.4.4 Plotting Results:

After the simulation is finish, go to Planer EM>Result>Create Report and plotting S11 which shows the return loss as in Figure 3.4.17.



Figure 3.4.15. Numerical return and insertion loss.

Radiation Pattern Plotting:

In the Project Window, right click Results > Create Report > Type: Far Field, Display Type:

Radiation Pattern then go to the Sweeps Tab, highlight the "F Point(s)" row, unclick All Values,

Highlight only 2.4GHz as shown in figure 3.4.18. Then go to the Mag tab and select Category: Gain, Quantity: GainEThetaAccepted, Function: dB then push add trace then OK. The result is the radiation pattern as shown in Figure 3.4.19.

Sweep 2	Manuff Comparation	×
Type	Sweep Description Single Value at 2.4GHz	
Specify Frequency Sweep Single value Linear step Linear count Decade count Value: 2.4 GHz V	Add >> Update >> Delete	
Setup Full Wave Spice	View Sweep Points List OK Car	icel

Figure 3.4.16. Single value at 2.4 GHz in frequency sweep window.



Figure 3.4.17. Far-field pattern at 2.4 GHz.

3.5 Project's Flow Chart.



Chapter 4

Microstrip antenna performance with different types of feeding techniques.

4.1 Introduction.

- 4.2 Design Procedure.
- 4.3 Results and discussion.

Chapter Four

Rectangular Microstrip Antenna Performance With Different Types of Feeding Techniques.

4.1 Introduction.

The microstrip patch antennas have been used since they are lightweight, compact and cost effective. The input impedance of these antennas depends on their geometrical shape, dimensions and the feed location.

Microstrip patch antennas have problems of low bandwidths. One of our goals is to show how to overcome this problem by using inset fed patch antenna. The purpose of the inset cut in the patch is to match the impedance of the feed line to the patch without the need for any additional matching element [19]. This is achieved by controlling the inset position.

Input impedance of the inset fed microstrip patch antenna mainly depends on the inset distance d and to some extent on the inset width, the fed patch antenna's input impedance is $cos^4 \left(\pi \frac{d}{l} \right)$ [19]. To achieve a better bandwidth is done by reducing the inset [20]. The inset feed is an easy feeding scheme, since it provides ease of fabrication and simplicity in modeling as well as impedance matching, because of these reasons the inset fed is better than the feed line technique.

This research is dedicated to simulate a rectangular inset fed patch antenna by using the software HFSS. Recently, due to growing demand of microwave. And wireless communication systems in various applications resulting in an interest to improve antenna performances.

Wireless local area networks (WLAN) require lightweight, small size and low cost antenna. WLAN in the 2.4 GHz band (2.4-2.438 GHz) has made rapid progress.

In this research, the research team tried to compare two types of feeding techniques, the inset feeding technique as shown in Fig 4.1 and the edge feeding technique as shown in Fig 4.2. This comparison aims to investigate which technique is better considering the bandwidth and the return loss, knowing that the dimensions and the dielectric material of the microstrip antenna will be the same for the two feeding types.

Fig.4.1 shows the patch geometry of an inset fed rectangular patch, where the notch width 'g' is located symmetrically along the width of the patch.



Fig.4.1.The inset fed patch geometry.

4.2Design Procedure:

4.2.1 Calculations of inset fed patch antenna:

The design procedure assumes that the specified information includes the dielectric constant of the substrate and the height of the substrate and is stated as:

1. Calculate the patch width (W_p) by using equation (4.1).

$$W_p = \frac{v_0}{2f_r} \sqrt{\frac{2}{\epsilon_r + 1}} \tag{4.1}$$

Where,

 V_0 : is the velocity of electromagnetic wave, 3×10^{11} mm/s, f_r is the resonant frequency, \in_r is the dielectric constant.

2. Calculate f_r that depends on notch width as:

$$f_r = \frac{v_o}{\sqrt{2 \times \epsilon_{reff}}} \frac{4.6 \times 10^{-14}}{g} + \frac{f}{1.01}$$
(4.2)

3. Calculate \in_r using this equation:

$$\epsilon_{reff} = \frac{\epsilon_r + 1}{2} + \frac{\epsilon_r - 1}{2} \left[1 + 12 \frac{h}{W_p} \right]^{-1/2}$$
 (4.3)

4. Calculate the patch length (L_P) as:

(4)
$$L_p = \frac{v_o}{2f_r \sqrt{\varepsilon_{reff}}} - 2\Delta L \qquad (4.4)$$

Where,

 \in_{reff} : is the effective dielectric constant and ΔL is the normalized extension of the length is given as:

$$\frac{\Delta L}{h} = 0.412 \frac{\left(\frac{W_p}{h} + 0.264\right)\left(\epsilon_{reff} + 0.3\right)}{\left(\epsilon_{reff} - 0.258\right)\left(\frac{W_p}{h} + 0.8\right)} \qquad (4.5)$$

Where,

h: is the height of the substrate.

5. Calculate the notch width g as:

$$g = \frac{v_o}{\sqrt{2 \times \epsilon_{reff}}} \frac{4.65 \times 10^{-12}}{f}$$
(4.6)

4.2.2 Calculation Fed with a Quarter-Wavelength Transmission Line (Edge Fed):

In the edge feed technique the microstrip antenna is matched to a transmission line of characteristic impedance Z_0 by using a quarter-wavelength transmission line of characteristic impedance Z_1 as shown in Figure 4.2.



Figure.4.2. Quarter wavelength fed patch antenna.

The goal is to match the input impedance (Z_{in}) to the transmission line (Z_0) . If the impedance of the antenna is Za, then the input impedance viewed from the beginning of the quarter-wavelength line becomes

 $Z_{in} = Z_o = Z_1^2 / Z_a$ (4.7)

This input impedance Z_{in} can be altered by selection of the Z_1 , so that $Z_{in}=Z_0$ the antenna is impedance matched. The parameter Z_1 can be altered by changing the width of the quarterwavelength strip. The wider the strip is, the lower the characteristic impedance (Z_0) is for that section of line. The impedance of the patch is given by:

$$Z_{a} = 90(\epsilon_{r}^{2}/(\epsilon_{r}-1))\left(\frac{k}{w}\right)^{2}$$
(4.8)

The characteristic impedance of the transition section should be:

$$Z_{\mathsf{T}} = \sqrt{Z_a * Z_0} \qquad (4.9)$$

The width of the transition line is calculated from (4.10):

$$Z_{\rm T} = \frac{60 \quad (\ln(\frac{8d}{Wt} + \frac{Wt}{4d}))}{\sqrt{\epsilon r}} \qquad(4.10)$$

4.2.3 Design Of Rectangular Microstrip Inset Feed line:

Rectangular microstrip patch has been designed using FR4 epoxy of \in_r =4.4 and h=1.5 mm. It is decided to design the rectangular patch for 2.4 GHz, the patch antenna has length (L) of 3.8 cm and its width (W_p) of 2.95cm and its resonant frequency of 2.4GHz, one of 15 designs of inset fed patch is shown if Fig.4.3



Figure 4.3. Design of inset fed patch microstrip antenna.

In this research 15 designs of inset fed patch were made to understand the tuning results of antenna. The research team analyzed the characterization of resonance frequencies as a function of notch width for an inset fed microstrip antenna.

4.2.4 Design of Rectangular Microstrip Quarter Length (edge feed) Line:

Rectangular microstrip edge feed patch has been designed with the same dimensions of inset fed patch antenna to show the differences between both of them and which one is better according bandwidth and return loss, the designers used FR4 epoxy of \in_r =4.4 and h=1.5 mm. It is decided to design the rectangular patch for 2.4 GHz, the patch antenna has length (L) of 3.8 cm and its width (W_p) of 2.95cm and it's resonant frequency of 2.4GHz, the design of the edge feed is shown in Fig 4.4



Fig.4.4. The design of the edge feed patch microstrip antenna.

4.2.5 Design of Coaxial cable feed of Patch Antenna.

Rectangular microstrip with coaxial cable feed of Patch Antenna has been designed, to operate from 2 GHz to 12 GHz, the rectangular microstrip antenna is chosen as it is by far the most widely used configuration in microstrip Antenna design. A MPA consists of a conducting Patch of any planar or no planar geometry on one side of a dielectric substrate (duriod5880 substrate) with a Ground plane on the other side as shown in figure 4.5.



Figure 4.5 Coaxial cable feed of Patch Antenna.

4.2.6 Design of Proximity-Coupled Microstrip Antenna.

We have designed a square patch multilayer proximity coupled microstrip antenna it operates at 13 GHz. Having a length and width of the patch is L=W=13mm. We have used feed substrate with dielectric medium of 3.2 and dielectric medium for antenna substrate is 2.33 and have an air gap of height 2.2mm with dielectric medium 1.10 as seen in figure 4.6.



Figure 4.6. Proximity-Coupled Microstrip Antenna.

4.3 Results and discussion:

Here we are comparing only return loss, resonance frequency and bandwidth of inset fed patch designs. We are trying to improve the bandwidth through varying inset distance and inset gap of microstrip Inset fed Patch Antenna, The values of inset width 'g' is changed with a ratio of W_f /5=0.574mm, W_f /10=0.287mm, W_f /20=0.1435mm, W_f /30=0.0956mm, W_f /40=0.07175mm, and the value of inset distance 'L' is changed with d= W_f =2.87mm, d=2 W_f =5.74mm, d =3 W_f =8.61mm, d=4 W_f =11.48, where W_f is the width of the feed line and equals 2.87mm.

It was observed that with a decrease in notch width 'g' from $W_f/5$ to $W_f/40$, the bandwidth is increased and improved (as shown in Fig.4.7) and the resonant frequency shifts away from 2.4 GHz(as shown in Fig.4.8), where g varies from 0.0717 to 0.574mm. The narrower notch the better the impedance match that we have as seen in Fig 4.8. The bigger inset distance the better bandwidth that we have as shown in figures 4.9, 4.10. The optimized results of return loss, bandwidth and resonance frequency for these designs are tabulated in table 4.1.

When comparing of two types of feeding techniques the research team concluded that the inset feed is better than the edge feed technique in the bandwidth and the return loss, in the edge feed patch design we get -12dB return loss and 0.0292 Bw as shown in Fig.4.11, and these results are worse than the result we have in inset fed patch antenna , all designs of inset fed patch antenna have a Bandwidth values that vary from 0.0505 to 0.0698 GHz , and the return loss reach -43.6dB when d=2wf and g=wf/10 as shown in Fig.4.12, this means that the radiation is much better than the radiation resulted in edge feed.



Fig.4.7. The relationship between the Bandwidth and the inset gap 'g' at L= W_f , L= $2W_f$, L= $3W_f$ and L= $4W_f$.



Figure 4.8. The relationship between resonant frequency and notch width "g"



Figure 4.9. The relationship between bandwidth and inset distance "d" for g=Wf/40.



Figure 4.10. The relationship between bandwidth and inset distance "d" for g=Wf/5.


Performance properties		S ₁₁ (dB)	-10 dB Bandwidth	Resonance
			%	frequency
			Duy	(GHz)
			$(\frac{BW}{fr} * 100\%)$	
			<u> </u>	
d=W _f	$g = W_f / 5$	-22.2	2.25%	2.3173
	,			
	$g = W_f / 10$	-29.7	2.38%	2.3468
	$g = W_f / 20$	-29.2	2.05%	2.3675
	$a = \frac{1}{2}$	22.0	2.05%	2 2056
	$g = W_f / 50$	-23.0	2.03%	2.5950
	$g = W_{\epsilon}/40$	-22.6	2.65%	2.4032
	8			
d=2 <i>W_f</i>	$g = W_f / 5$	-19.3	2.38%	2.3254
	$g = W_f / 10$	-43.6	2.51%	2.3701
	147. (20	25	2 540/	2 2012
	$g = W_f / 20$	-25	2.51%	2.3912
	$\sigma = W_{c}/30$	_21	2.64%	2 3967
	g - W _f /30	21	2.0470	2.3507
	$g = W_f / 40$	-19.7	2.77%	2.400
	C <i>j</i> .			
d=3 <i>W_f</i>	$g = W_f / 5$	-24.636	2.38%	2.3374
	$g = W_f / 10$	-40	2.38%	2.3562
	$a = \frac{1}{2}$	22.00	2 6 4 9/	2 2916
	$g = W_f/20$	-32.88	2.04%	2.3810
	$g = W_{f}/30$	-31	2.67%	2.3865
	8			
	$g = W_f / 40$	-27.16	2.78%	2.4032
	,			
d=4 <i>W_f</i>	$g = W_f / 5$	-16.5	2.43%	2.3708
		20.65	2.650/	2 2 2 2 2 2
	$g = VV_f / 10$	-20.65	2.65%	2.3823
	$\sigma = W_c/20$	-25 714	2 77%	2 3801
	δ ⁻ "f/20	23.7 14	2.7770	2.3034
	$g = W_f / 30$	-20.6477	2.91%	2.3952
	- <u>,</u> .			
	$g = W_f / 40$	-17.694	2.91%	2.400

4.3.1 Return loss.



Figuer4.11.The return loss of the edge feed patch microstrip antenna.



Fig.4.12. Return loss when $L=2W_f$ and $g = W_f/10$.

The following Figures shows the inset fed patch Return loss, bandwidth and resonance frequency when d=4W_f and g=W_f/5, g=W_f/10, g=W_f/20, g=W_f/30, g=W_f/40.



Fig.4.13. Return loss when L=4 W_f and g = $W_f/5$.



Fig.4.14. Return loss when L=4 W_f and g = $W_f/10$.



Fig.4.15 Return loss when L=4 W_f and g = $W_f/20$.



Fig.4.16 Return loss when L=4 W_f and g = $W_f/30$.



Fig.4.17 Return loss when L=4 W_f and g = $W_f/40$.

Figure 4.18 shows return loss through range of frequency (1- 4 GHz) having single band at 2.36 GHz with return loss (RL=-28 dB), but when we increased the band, multi operated bands appear as shown in figure 4.19.



Figure 4.18 S-parameter (dB) versus Frequency (1-4 GHz).



Figure 4.19 S-parameter (dB) versus Frequency (GHz).

Figure 4.19 shows operated bands of our patch antenna which are 2.38 GHz, 4.74 GHz, 7.09 GHz, 8 GHz and 9.74 GHz of return loss (RL= -13 dB, -18.1 dB,-16.5 dB,-25.5 dB, and -17.4 dB) respectively.

The best radiation of the antenna occurs at 8 GHz, where S11= -25.5 dB, at 2 GHz the antenna will radiate virtually nothing, as S11 is close to 0 dB.

In Proximity-coupled Feed matching can be achieved by controlling the length of the feed line, the results obtained are frequency: 13.3 GHz, return loss: -20 dB as shown in figure 4.20.



Figure 4.20. Return loss at the resonant frequency.

4.3.2 Radiation Pattern of Rectangular Microstrip Inset Feed line and proximity coupled feed.



Figure.4.21 Radiation pattern phi 0 and 90 E-plane for d = Wf and g = W / 40.



Figure .4.22 Radiation pattern phi 0 and 90 E-plane for d=Wf and g = $W_f/5$.



Figure.4.23 Radiation pattern phi 0 and 90 E-plane for d=Wf and g = $W_f/30$.



Figure.4.24 Radiation pattern phi 0 and 90 E-plane for d=4Wf and g = $W_f/40$.







Chapter five

Result and Conclusion

5.1 An Overview.

5.2 Conclusion.

Chapter five

Result and Conclusion

5.1. An overview.

This chapter is devoted to summarize the results obtained during the simulation process.

5.2 Conclusions.

The following points present the main results of the simulation process through the project:

- 1. As it was observed with a decrease in notch width of the inset feed the bandwidth increased and the resonant frequency shifts away from 2.4 GHz, where g varies from 0.0717 to 0.574mm.
- 2. When comparing the two types of feeding techniques ;(the inset feed and the edge feed) it was concluded that the inset feed is better than the edge feed technique in the bandwidth and the return los. In the edge feed patch design the results were -12dB return loss and 0.0292GHz BW, and these results are worse than the result in the inset fed patch antenna.
- 3. The radiation of inset feed is better than the radiation obtained in edge feed.
- 4. The narrower notch the better the impedance match that results. By controlling the inset distance of the feed line between two substrates of proximity coupled feed the matching in microstrip antenna will be controlled leading to an improved the return loss.
- 5. As an extra work, we design a rectangular patch coaxial feed microstrip antenna at frequency range from 2GHz to 12GHz, and we obtained the best resonant frequency at 8GHz, which gives return loss of -25.5 dB,but at 2 GHz the antenna will radiate virtually nothing, as S11 is close to 0 dB.

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